ATTORNEY/DOCKET NO:

DECLARATION FOR PATENT APPLICATION AND APPOINTMENT OF ATTORNEY

As a below named inventor, I hereby declare that my residence, post office address and citizenship are as stated below next to my name; I believe that I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention (Design, if applicable) entitled:

Method for lift off GaN pseudomask epitaxy layer using wafer bonding way

the specification of which (check	was filed was amended of and understand the Lacknowledge the greby claim foreign and below and have a	on: contents of the duty to disclose priority benefits	intornation white	ch is material to patentability as	ms, as amend defined in Tit	ed by any tle 37, Code o		
	(8)		PRIORITY CLAIMED					
Number	Number Country			Day/Month/Year Filed	Yes	No		

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I HEREBY CLAIM THE BEN	FIT UNDER TITLE 3	5 U.S. CODE §	119(E) OF ANY L	J.S. PROVISIONAL APPLICATIONS	LISTED BELO	w.		
Application Number			Day/Month/Year Filed					
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sclose information which is material to patentability as defined in Turk e tiling date of the prior application(s) and the national or PCT international or			ational rang date of this application:					
Application Number	Application Number Filling De		ite	Status - Patented, Pendir	loned			
	Additional US/F	CT Priority App	olication(s) listed	on Following Page(s)				
punishable by fine or imprisonment jeopardize the validity of the application	or both, under secretion or any patent i I (We) hereby agrees in the Patent ar	ion 1001 of title ssued thereon, ppoint as my (ound nd Trademark Of	18 of the United	States Code and that such willful powers of substitution and therewith:	like so made a il false staten	arc nents may		
(we) authorize my(our) attomeys to elated to the preparation, examinati hereon, and any patent resulting the	accept and follow i	nstructions from	nlicolina anni	rels IPR Law Firm re	garding any r or divisional	natter based		
Send correspondence to:		ROXELL LAW OFFICE PLLC		TELEPHONE CALLS TO:				
	PIKE, SUITE 140 VA. 22041	4	BRUCE H. TROXELL (703) 575-2711					
FULL NAME OF FIRST OR SOLE INVENTOR			CITIZENSHIP		and a second sec			
Yew-Chung Wu RESIDENCE ADDRESS			Ta	iwan, R.O.C	·			
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See following page(s) for additional joint inventors.

SIGNATURE

2003/11/08

ATTORNEY/DOCKET NO: CONTINUATION OF DECLARATION FOR PATENT APPLICATION AND APPOINTMENT OF ATTORNEY

Page 2

PRI	USC §119	SC § 119) PRIORITY CLAIMED										
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PRIOR PROVISIONAL APPLICATIONS 35 U.S. CODE § 119(E)												
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PRIOR U.S. OR PCT INTERNATIONAL APPLICATIONS (35 U.S. CODE \$120)												
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		Timing Date										
			*									
FULL NAME OF JOINT INVENTOR Pei-Yen Lin			Citizenship Talwan, R.O.C.									
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DATE 2003/11/8			SIGNATURE 20 M									
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FULL NAME OF JOINT INVENTOR			CITIZENSHIP									
Hsien-Chih Peng			Taiwan, R.O.C.									
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 $[\]square$ See following pages for additional joint inventors/priority applications.

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